
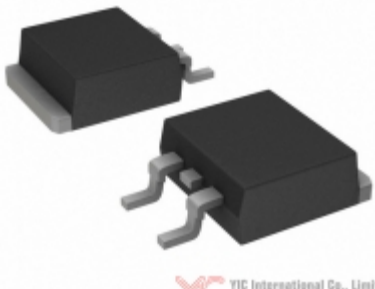
	<h2 style="color: red;">FQB55N06TM</h2>
	<p><b>Hersteller-Teilenummer:</b> FQB55N06TM</p> <hr/> <p><b>Hersteller / Marke:</b> Fairchild/ON Semiconductor</p> <hr/> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 60V 55A D2PAK</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">FQB55N06TM.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 60725 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQB55N06TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 60V 55A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	60725 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 133W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	55A (Tc)
Rds On (Max) @ Id, Vgs	20 mOhm @ 27.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	46nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1690pF @ 25V
Verpackung	Tape & Reel (TR)






FQB55N06TM ist neu im Original, Suche FQB55N06TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB55N06TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB55N06TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQB50N06TM</b> Fairchild/ON Semiconductor MOSFET N-CH 60V 50A D2PAK</p>	 <p><b>FQB50N06TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 50A D2PAK</p>	 <p><b>FQB50N06TM-NL</b> VB FQB50N06TM-NL VB</p>	 <p><b>FQB55N10TM</b> Fairchild/ON Semiconductor MOSFET N-CH 100V 55A D2PAK</p>
 <p><b>FQB52N25</b> FAIRCHILD FAIRCHILD TO-263</p>	 <p><b>FQB55N10</b> FAIRCHILD FQB55N10 FAIRCHILD</p>	 <p><b>FQB55N10TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 55A D2PAK</p>	 <p><b>FQB55N06TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 55A D2PAK</p>

### heiße Teile

Mehr

 FQB4N20TM	 FQB4N20TM	 FQB4N25TM	 FQB4N25TM	 FQB4N20TM
 FQB4N50TM	 FQB4N50TM	 FQB4N60C	 FQB4N80TM	 FQB4N80TM
 FQB4N90TM	 FQB4N90TM	 FQB4P25TM	 FQB4P25TM	 FQB50N03
 FQB50N06	 FQB50N06C	 FQB50N06L	 FQB50N06LTM	 FQB50N06LTM
 FQB50N06M	 FQB50N06TM	 FQB50N06TM	 FQB50N06TM-NL	 FQB55N06TM
 FQB55N10	 FQB55N10TM	 FQB55N10TM	 FQB5N20L	 FQB5N30TM
 FQB5N30TM	 FQB5N50C	 FQB5N50CF	 FQB5N50CTM	 FQB5N50CTM
 FQB5N60CTM	 FQB5N60CTM	 FQB5N90TM	 FQB5N90TM	 FQB5P10TM
 FQB5P10TM	 FQB630TM	 FQB630TM	 FQB65N06	 FQB65N06TM
 FQB65N06TM	 FQB6N40C	 FQB6N40CF	 FQB6N40CTM	 FQB6N40CTM

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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